

Messrs. Rockwell Automation

# SPECIFICATION

Device Name : IGBT Module

Type Name : 7MBR30SA060E-01

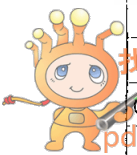
Spec. No. : MS6M 0543

Date : Jun. - 02 - 2000

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Fuji Electric Co., Ltd.  
Matsumoto Factory

DATE	NAME	APPROVED	Fuji Electric Co., Ltd.	
DRAWN: Jun - 2 - '00	J. Kobayashi	T. Miyata	MS6M 0543	1 / 10
CHECKED: Jun - 2 - '00	S. Naito			
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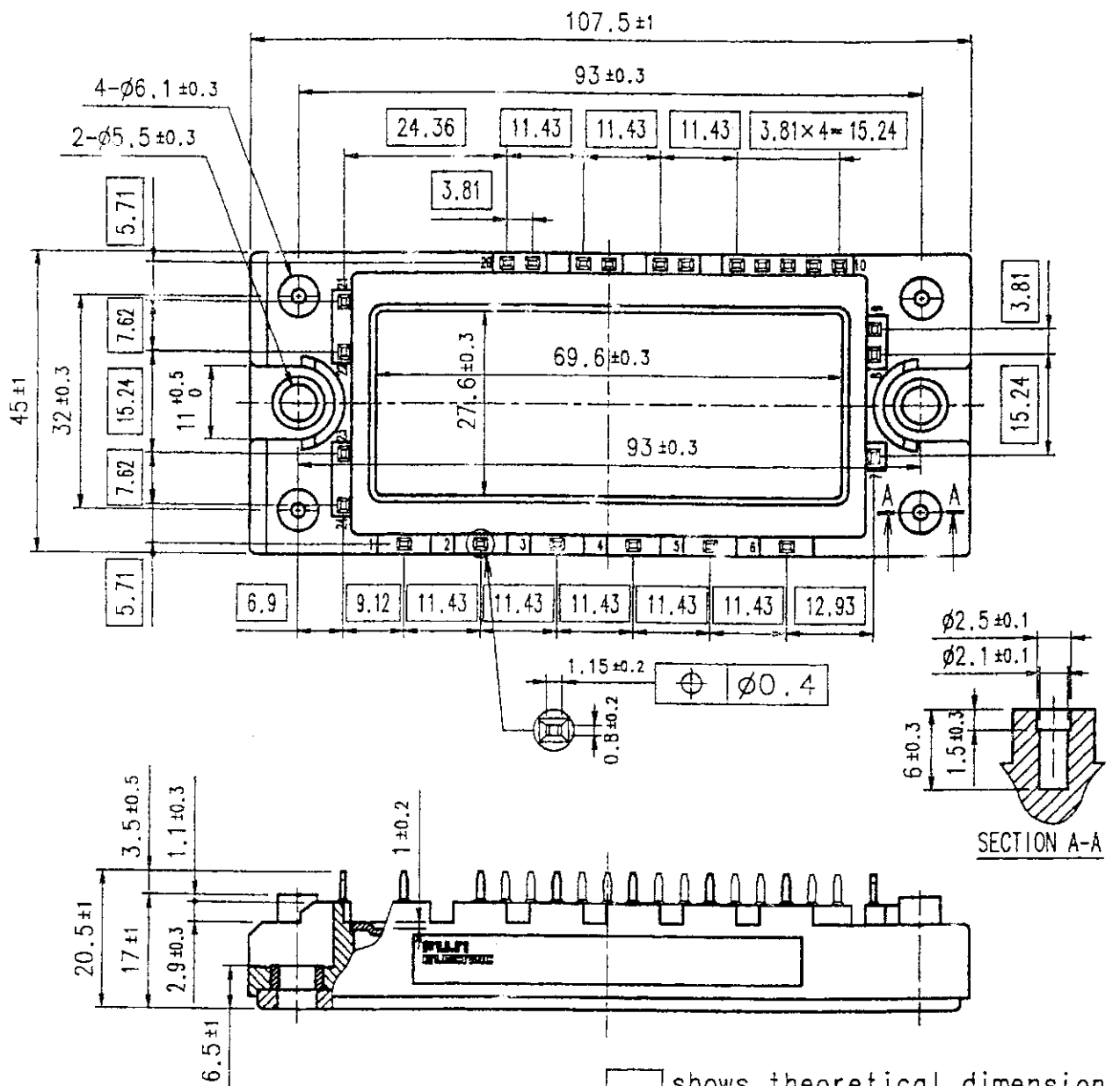
# Revised Records

Date	Classi- fication	Ind.	Content	Applied date	Drawn	Checked	Approved
Jan-2-'00	enactment	—	—————	Issued date	—	<i>S. Matsu</i>	<i>T. Miyasaka</i>

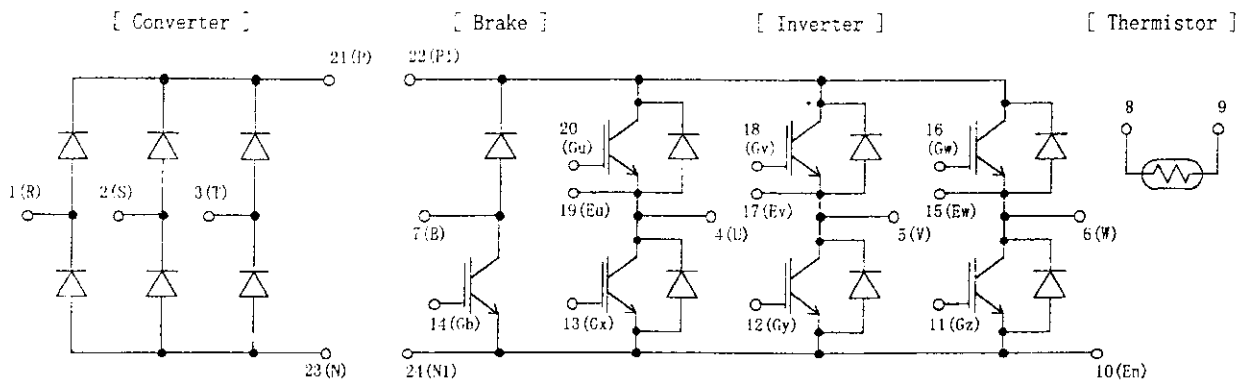
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7MBR30SA060E-01

1. Outline Drawing ( Unit : mm )



2. Equivalent circuit



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3. Absolute Maximum Ratings ( at Tc= 25C unless otherwise specified)

Items		Symbols	Conditions	Maximum Ratings	Units
Inverter	Collector-Emitter voltage	VCES		600	V
	Gate-Emitter voltage	VGES		+ -20	V
	Collector current	lc	Continuous	30	A
		lcp	1ms	60	A
		-lc		30	A
Collector Power Dissipation	Pc	1 device	120	W	
Brake	Collector-Emitter voltage	VCES		600	V
	Gate-Emitter voltage	VGES		+ -20	V
	Collector current	lc	Continuous	20	A
		lcp	1ms	40	A
	Collector Power Dissipation	Pc	1 device	80	W
	Repetitive peak reverse Voltage(Diode)	VRRM		600	V
Converter	Repetitive peak reverse Voltage	VRRM		800	V
	Average Output Current	Io	50Hz/60Hz sine wave	50	A
	Surge Current (Non-Repetitive)	IFSM	Tj= 150C, 10ms	350	A
	I <sup>2</sup> t (Non-Repetitive)	I <sup>2</sup> t	half sine wave	613	A <sup>2</sup> s
Junction temperature		Tj		150	C
Storage temperature		Tstg		-40~ +125	C
Isolation voltage	between terminal and copper base <sup>(*)1</sup>	Viso	AC : 1min.	2500	V
	between thermistor and others <sup>(*)2</sup>			2500	V
Mounting Screw Torque <sup>(*)3</sup>				3.5	Nm

(\*1) All terminals should be connected together when isolation test will be done.

(\*2) Terminal 8 and 9 should be connected together. Terminal 1 to 7 and 10 to 24 should be connected together and shorted to copper base.

(\*3) Recommendable Value : 2.5~3.5 Nm (M5)

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4. Electrical characteristics ( at Tj= 25C unless otherwise specified)

Items	Symbols	Conditions	Characteristics			Units					
			min.	typ.	Max.						
Inverter	Zero gate voltage Collector current	ICES	VGE	0 V, VCE	600 V	1.0	mA				
	Gate-Emitter leakage current	IGES	VCE	0 V, VGE	+20 V	200	nA				
	Gate-Emitter threshold voltage	VGE(th)	VCE	20 V, Ic =	30 mA	5.5	7.8	8.5	V		
	Collector-Emitter saturation voltage	VCE(sat)	VGE	15 V, Ic =	chip		1.8		V		
					terminal		1.95	2.4			
	Input capacitance	Cies	VGE	0 V, VCE	10 V		3000		pF		
	Turn-on time	ton	Vcc=	300 V	Ic =	30 A			0.45	1.2	us
									0.25	0.6	
									0.08		
	Turn-off time	toff	RG =	82 ohm					0.40	1.0	
0.05									0.35		
Forward on voltage	VF	IF =	30 A					1.8		V	
								1.95	2.6		
Reverse recovery time	trr	IF =	30 A					300	ns		
Brake	Zero gate voltage Collector current	ICES	VGE	0 V, VCE	600 V	1.0	nA				
	Gate-Emitter leakage current	IGES	VCE	0 V, VGE	+20 V	200	nA				
	Collector-Emitter saturation voltage	VCE(sat)	VGE	15 V, Ic =	chip		1.8		V		
					terminal		1.95	2.4			
	Turn-on time	ton	Vcc=	300 V	Ic =	20 A			0.45	1.2	us
									0.25	0.6	
	Turn-off time	toff	VGE	+15 V					0.40	1.0	
0.05									0.35		
Reverse current	IRRM	VR =	600 V					1.0	mA		
Converter	Forward on voltage	VFM	IF =	30 A				1.0		V	
								1.1	1.5		
Reverse current	IRRM	VR =	800 V					1.0	mA		
Thermistor	Resistance	R	T =	25C			5000		ohm		
			T =	100C	465	495	520				
B value	B	T =	25/50C	3305	3375	3450		K			

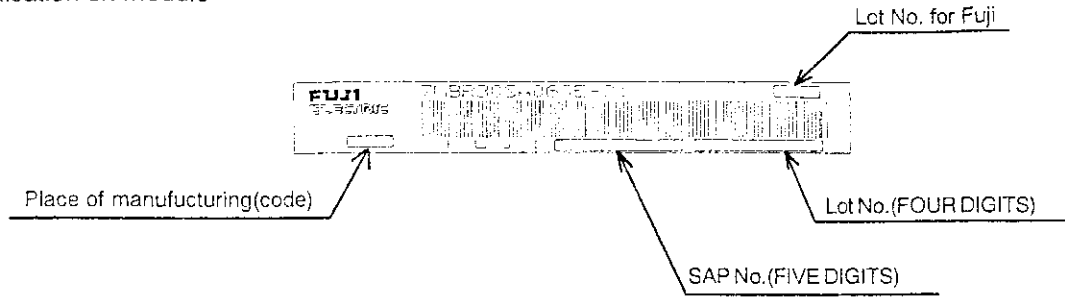
5. Thermal resistance characteristics

Items	Symbols	Conditions	Characteristics			Units
			min.	typ.	Max.	
Thermal resistance (1 device)	Rth(j-c)	Inverter IGBT			1.04	C/W
		Inverter FWD			2.00	
		Brake IGBT			1.56	
		Converter Diode			0.90	
Contact Thermal resistance	Rth(c-f)	with Thermal Compound (*)		0.05		C/W

\* This is the value which is defined mounting on the additional cooling fin with thermal compound.

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6. Indication on module



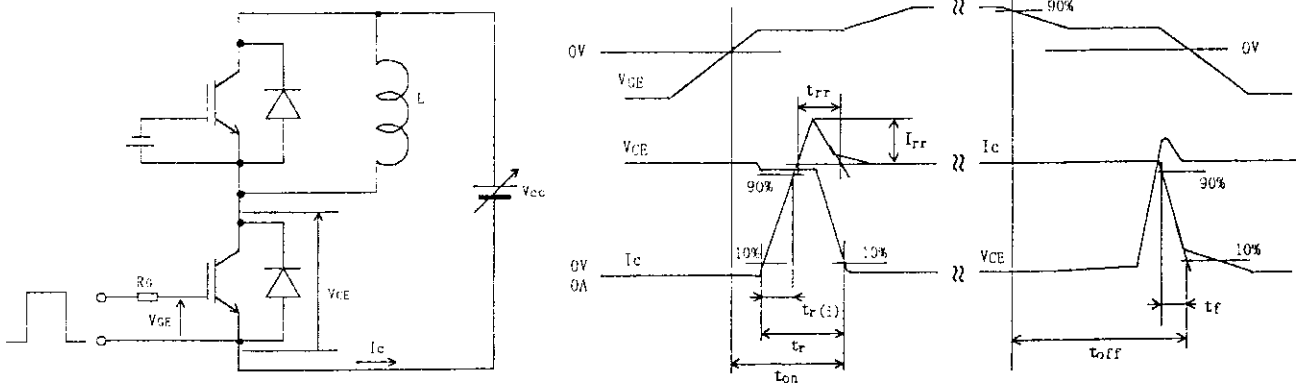
7. Applicable category

This specification is applied to Power Integrated Module named 7MBR30SA060E-01.

8. Storage and transportation notes

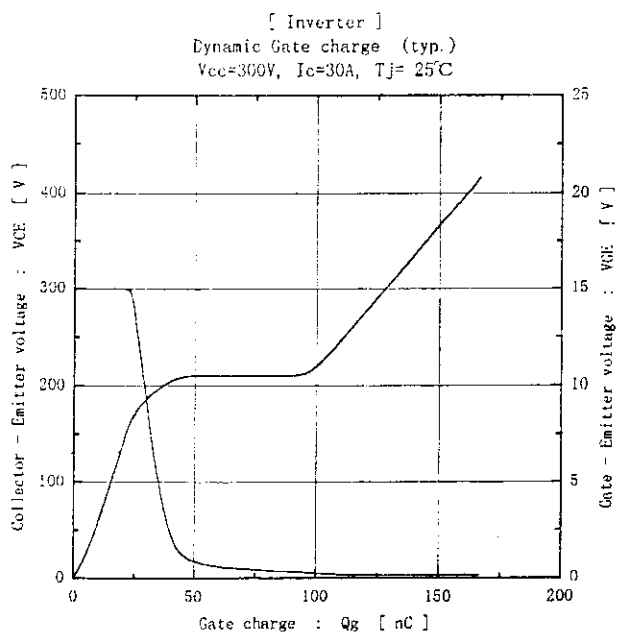
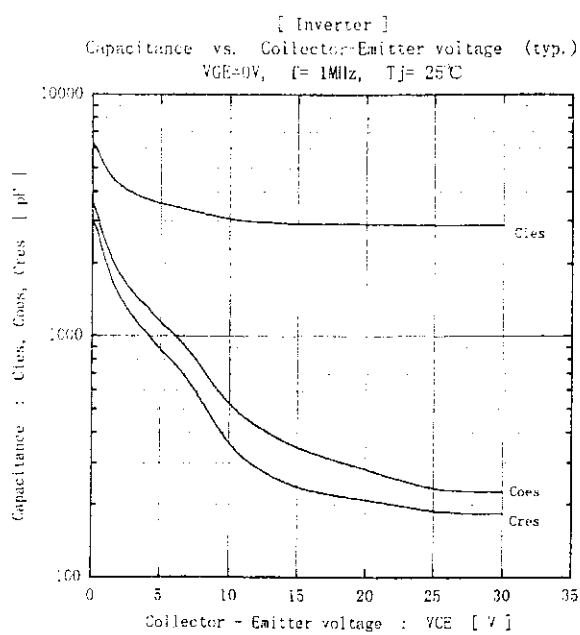
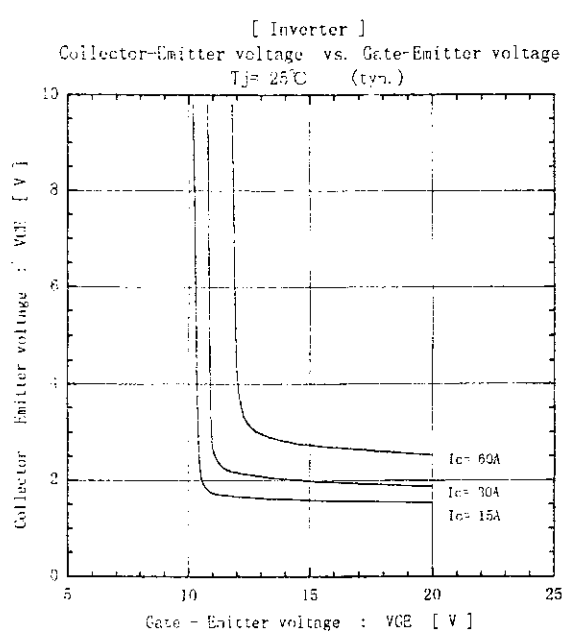
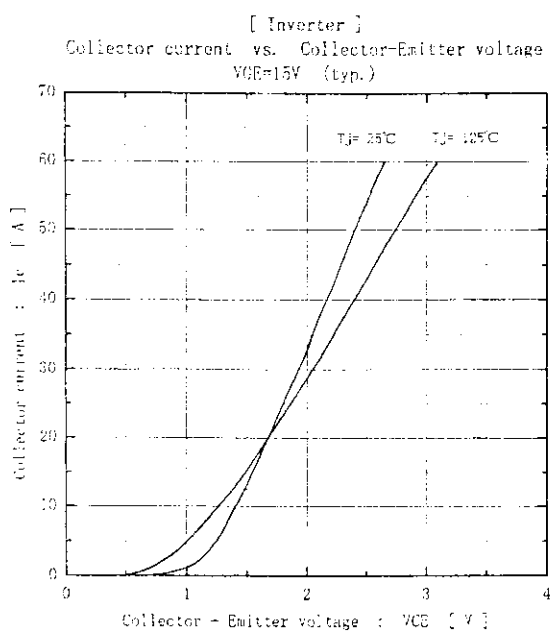
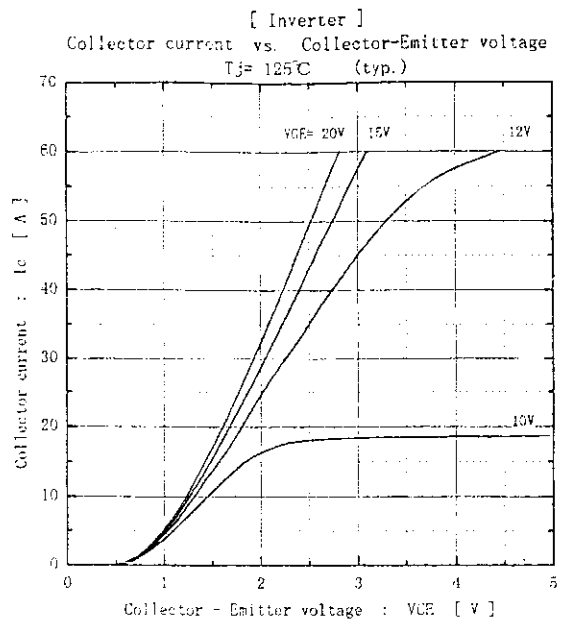
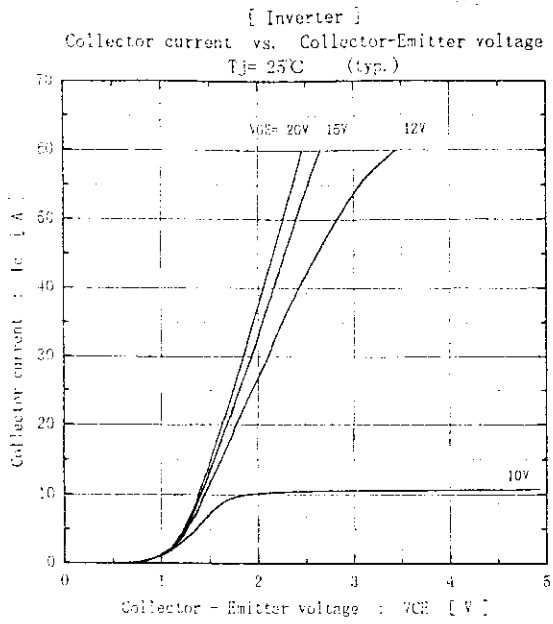
- The module should be stored at a standard temperature of 5 to 35°C and humidity of 45 to 75% .
- Store modules in a place with few temperature changes in order to avoid condensation on the module surface.
- Avoid exposure to corrosive gases and dust.
- Avoid excessive external force on the module.
- Store modules with unprocessed terminals.
- Do not drop or otherwise shock the modules when transporting.
- Please connect adequate fuse or protector of circuit between three-phase line and this product to prevent the equipment from causing secondary destruction.

9. Definitions of switching time

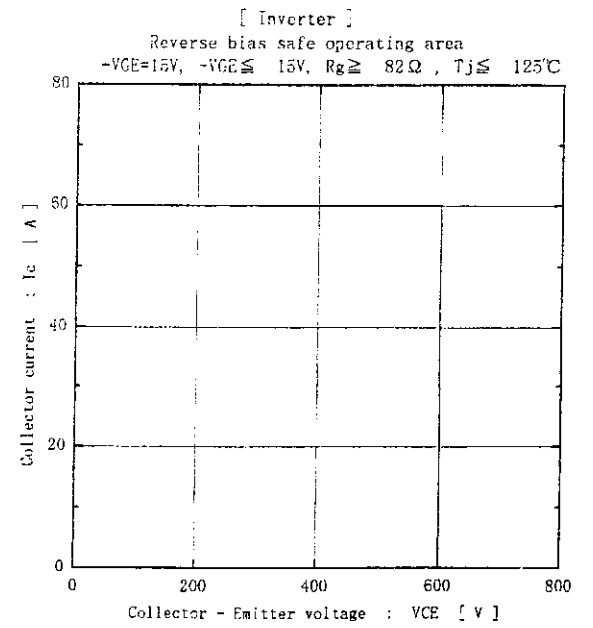
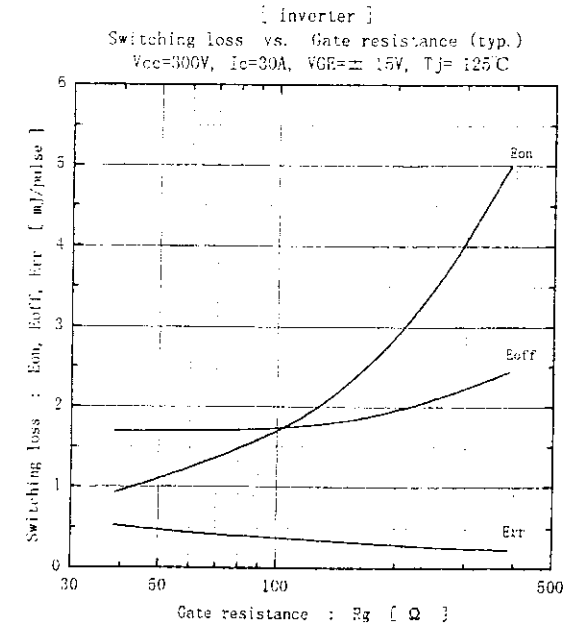
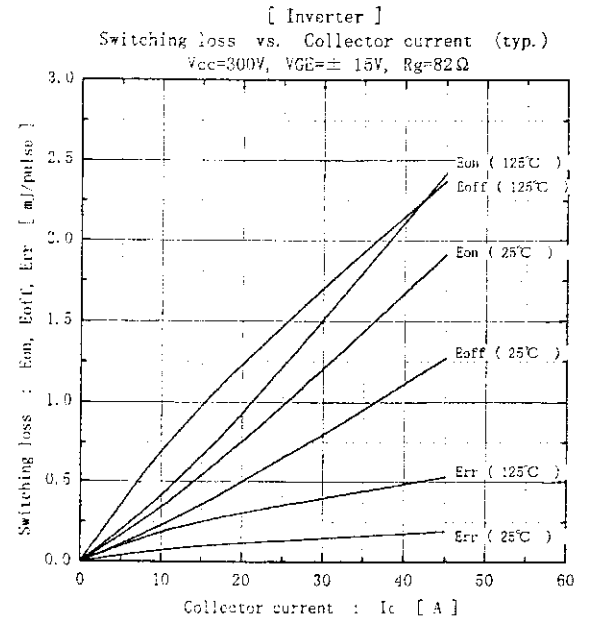
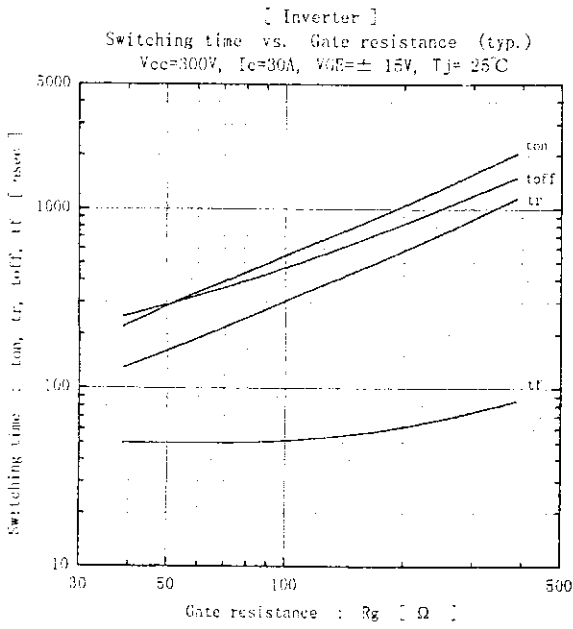
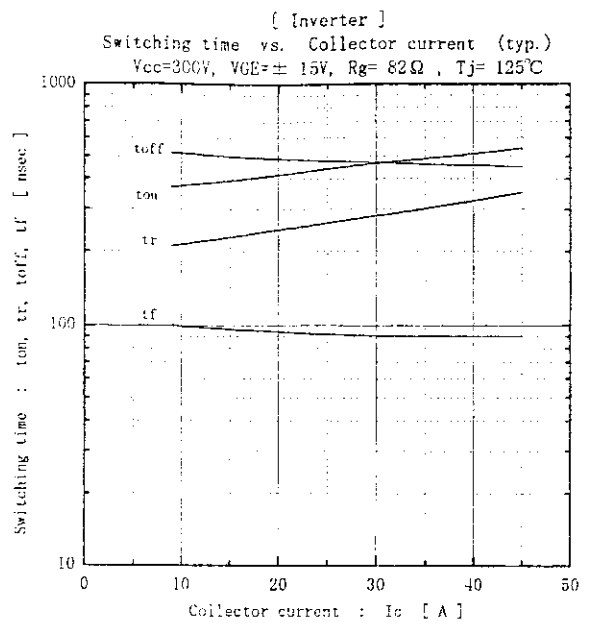
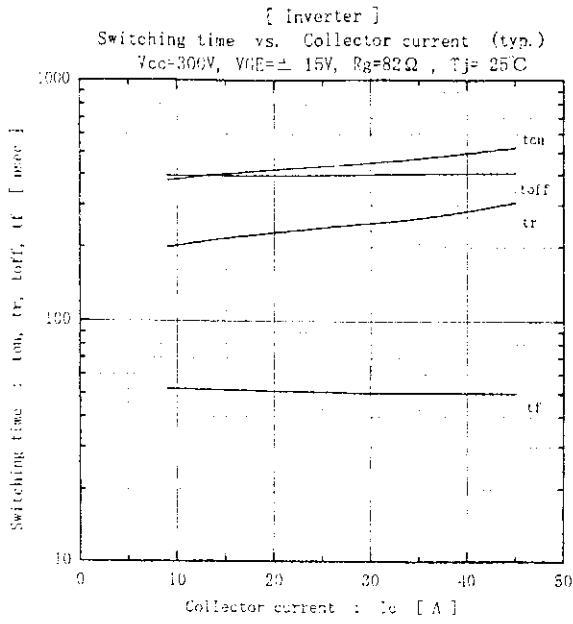


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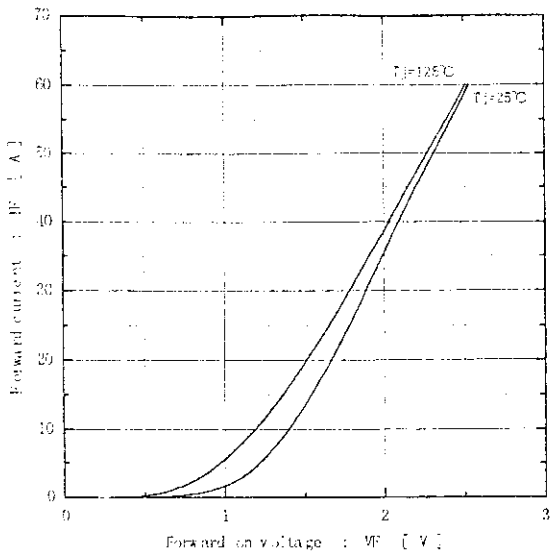
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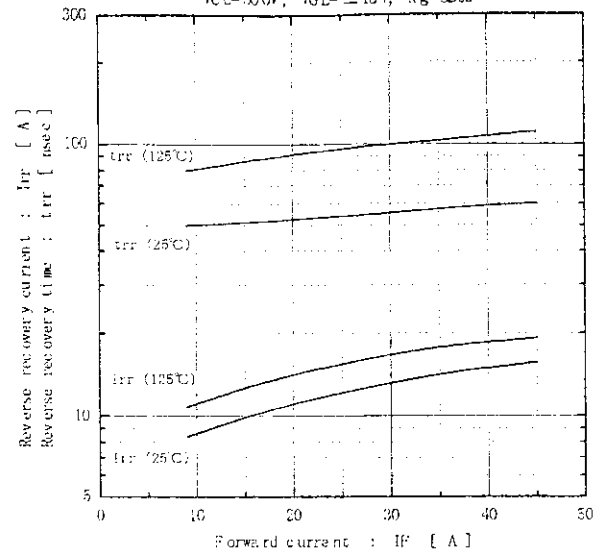


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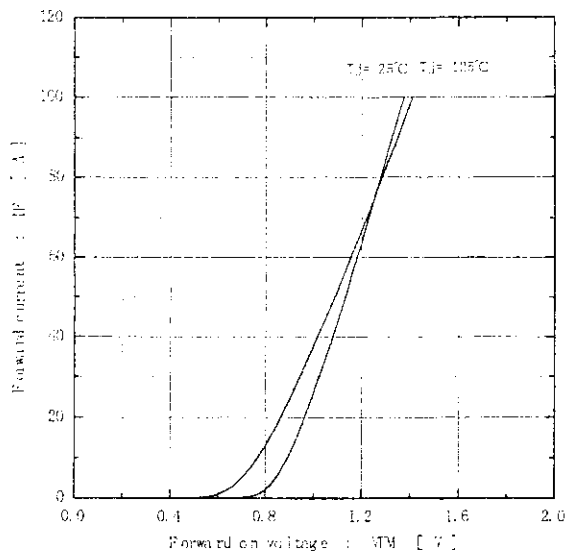
[ Inverter ]  
Forward current vs. Forward on voltage (typ.)



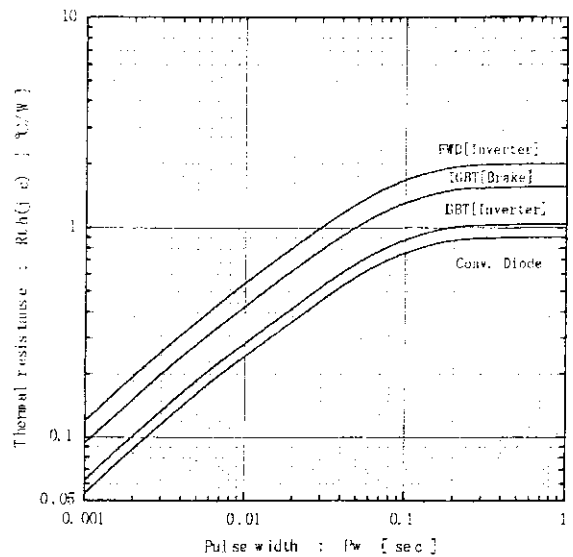
[ Inverter ]  
Reverse recovery characteristics (typ.)  
 $V_{ce} = 100V, V_{GE} = \pm 15V, R_g = 82\Omega$



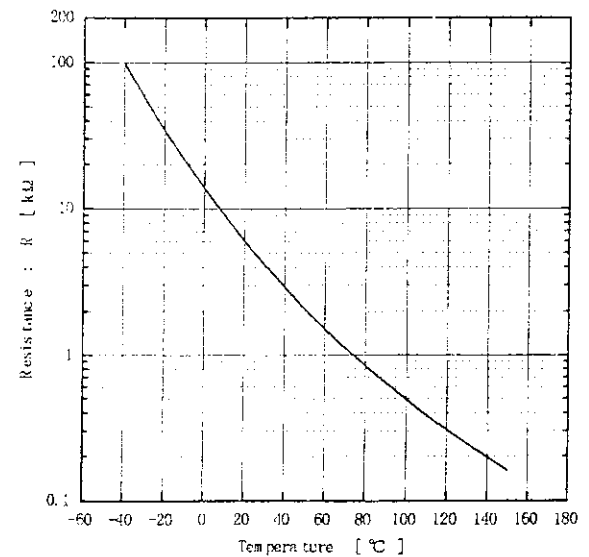
[ Converter ]  
Forward current vs. Forward on voltage (typ.)



Transient thermal resistance



[ Thermistor ]  
Temperature characteristic (typ.)



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